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100mA Low Dropout Voltage Regulators

PL2951-XXQ8

FEATURES

- Battery powered systems
- Cordless telephones
- Radio control systems
- Portable/Palm top/Notebook computers
- Portable consumer equipment
- Portable Instrumentation
- Avionics
- Automotive Electronics
- SMPS Post-Regulator
- Voltage Reference

APPLICATIONS

- High accuracy output voltage
- Guaranteed 100mA output
- Very low quiescent current
- Low dropout voltage
- Extremely tight load and line regulation
- Very low temperature coefficient
- Needs only 1µF for stability
- Error Flag warns of output dropout
- Logic-Controlled electronic shutdown
- Output programmable from 1.24 to 29V

PRODUCT DESCRIPTION

The PL2951-XX is a low power voltage regulator. This device excellent choice for use in battery powered application such as cordless telephone, radio control systems, and portable computers.

The PL2951-XX features very low quiescent current ($75\mu A$ Typ.) and very low drop output voltage (Typ. 40mV at light load and 380mV at 100mA). This includes a tight initial tolerance of 0.5% typ., extremely good load and line regulation of 0.05% typ., and very low output temperature coefficient, making the PL2951-XX useful as a low-power voltage reference.

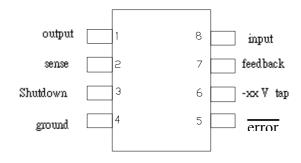
The error flag output feature is used as power-on reset for warn of a low output voltage, due to following batteries on input. Other feature is the logic-compatible shutdown input which enable the regulator to be switched on and off.

The PL2951-XX is available in 8-pin plastic packages. The regulator output voltage may be pin-strapped for a -XX volt or programmed from 1.24 volt to 29 volts with external pair of resistors.

Absolute Maximum Ratings

Power Dissipation	Internally Limited
Lead Temperature	260°C
(Soldering, 5 seconds)	
Storage Temperature Range	-65°C to+150°C
Operating Junction Temperature	-55°C to +150°C
Range	
Input Supply Voltage	-0.3 to $+30$ V
Feedback Input Voltage	-1.5 to +30V
Shutdown Input Voltage	-0.3 to +30V
Error Comparator Output	-0.3 to +30V

Pin Connection





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Device Selection Guide

Vout, Volts	Device
2.85*	PL2951-2.85
3.0	PL2951-3.0
3.3	PL2951-3.3
5.0	PL2951-5.0

* - other versions are also available

Vout = 2.0V to 5.0V. Please consult factory for more information

ELECTRICALCHARACTERISTICS (at Ta =25°C, =15V;unless otherwise noted)

Parameter	Conditions(Note 2)	itions(Note 2) Min			Units
Output Voltage	-25°C≤TJ≤85°C	0.985 Vo	Typ Vo	1.015 Vo	V
	Full Operating Temperature	0.98 Vo		1.02 Vo	
Output Voltage	100 μ A≤IL≤100mA,TJ≤TJMAX	0.976 Vo	Vo	1.024 Vo	
Output Voltage Temperature	(Note 1)	-	50	150	ppm/°C
Coefficient					
Line Regulation(Note 3)	Vo+1V≤Vin≤30V(Note 4)	-	0.04	0.4	%
Load Regulation(Note 3)	$100 \mu\text{A} \leq \text{IL} \leq 100 \text{mA}$	-	0.1	0.3	%
Dropout Voltage(Note 5)	IL=100 μ A	-	50	80	mV
	IL=100mA		380	450	
Ground Current	IL=100 μ A	-	75	120	MA
	IL=100 mA		8	12	mA
Dropout Ground Current	Vin=Vo-0.5V,IL=100 μ A	-	110	170	μΑ
Current Limit	Vout=0	-	160	200	mA
Thermal Regulation		-	0.05	0.2	%/W
Output Noise, 10Hz to 100KHz	CL=1 \(\mu\) F	_	430	_	μ Vrms
	CL=200 μ F		160		
	CL=3.3 μ F		100		
	(Bypass=0.01 μ F, pins 7 to 1)				
Reference Voltage	(Bypuss 0.01 \(\mu 1 \), pins \(\tau 1 \)	1.21	1.235	1.26	V
Reference Voltage	Over Temperature(Note 6)	1.185	-	1.285	·
Feedback Pin Bias Current	, and a first the second	-	20	40	nA
Reference Voltage Temperature	(Note 7)	-	50	-	ppm/°C
Coefficient					ppin c
Feedback Pin Bias Current		-	0.1	-	nA/°C
Temperature Coefficient					
Error Comparator			•		
Output Leakage Current	Voh=30V	-	0.01	1.0	μ A
Output Low Voltage	Vin=4.5V,IoL=400 μ A	-	150	250	
Upper Threshold Voltage	(Note 8)	40	60	-	mV
Lower Threshold Voltage	(Note 8)	-	75	95	
Hysteresis	(Note 8)	-	15	-	
Shutdown Input					
Input Logic Voltage	Low(Regulator ON)	-	1.3	0.7	V
	High(Regulator OFF)	2	-	-	
Shutdown Pin Input Current	Vs=2.4V	-	30	50	
D 1	Vs=30V	-	450	600	
Regulator Output Current in	(Note 9)	-	-	-	
Shutdown	VOUT=5V	-	3	10	μ A
	3.3V\(\leq\)VOUT\(\leq 5.0\)V 2.0V\(\leq\)VOUT\(\leq 3.3\)V	-	-	20	
	2.0 v \(\sigma\) 001\(\sigma\)3.3 V	-	-	30	



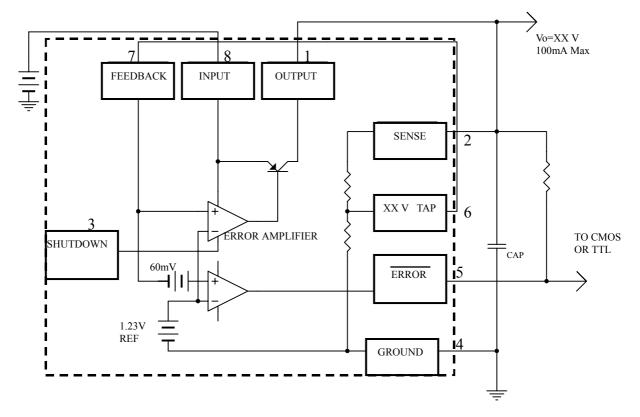
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- Note 1:Output or reference voltage temperature coefficients defined as the worse case voltage change divided by the total temperature range.
- Note 2:Unless otherwise specified all limits guaranteed for T_J=25°C, Vin=Vo+1V, I_L=100 μ A and C_L=1 μ F. Feedback pin tied to -XX V tap pin and output tied to output sense (Vout=XX V) and Vshutdown≤0.8V.
- Note 3.Regulations is measured at constant junction temperature, using pulse testing with a low duty cycle.

 Changes in output voltage due to heating effects are covered under the specification for thermal regulation.
- Note 4:Line regulation is tested at 150 $^{\circ}$ C for IL=1mA. For IL=100 μ A and TJ=125 $^{\circ}$ C, line regulation is guaranteed by design to 0.2%.
- Note 5:Dropout voltage is defined as the input to output differential at which the output voltage drops 100mV below its nominal value measured at 1V differential. At very low values of programmed output voltage, the minimum input supply voltage of 2V(2.3V over temperature) must be taken into account.
- Note 6:Vref \leq Vout \leq (Vin-1V),2.3V \leq Vin \leq 30V,100 μ A \leq IL \leq 100mA,TJ \leq TJMAX.
- Note 7:Output or reference voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
- Note 8:Comparator thresholds are expressed in terms of a voltage differential at the feedback terminal below the nominal reference voltage measured at Vo+1V input. To express these thresholds in terms of output voltage change, multiply by the error amplifier gain = Vout/Vin=(R1+R2)/R2. For example, at a programmed output voltage of 5V, the error output is guaranteed to go low when the output drops by 95mV×5V/1.235=384mV. Thresholds remain constant as a percent of Vout as Vout is varied, with the dropout warning occurring at typically 5% below nominal, 7.5% guaranteed.
- Note 9:Vshutdown≥2V, Vin≤30V, Vout=0, feedback pin tied to -XX V tap.

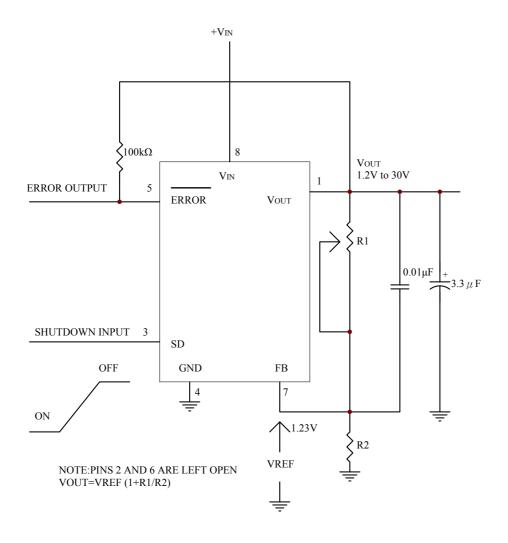
Block Diagram and Typical Applications





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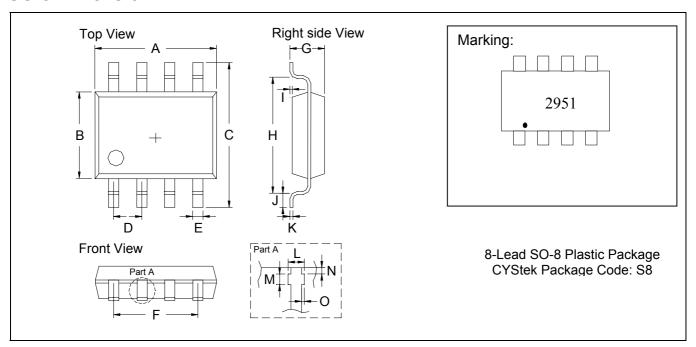




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SO-8 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.	DIIVI	Min.	Max.	Min.	Max.
Α	0.1909	0.2007	4.85	5.10	1	0.0019	0.0078	0.05	0.20
В	0.1515	0.1555	3.85	3.95	J	0.0118	0.0275	0.30	0.70
С	0.2283	0.2441	5.80	6.20	K	0.0074	0.0098	0.19	0.25
D	0.0480	0.0519	1.22	1.32	L	0.0145	0.0204	0.37	0.52
Е	0.0145	0.0185	0.37	0.47	М	0.0118	0.0197	0.30	0.50
F	0.1472	0.1527	3.74	3.88	N	0.0031	0.0051	0.08	0.13
G	0.0570	0.0649	1.45	1.65	0	0.0000	0.0059	0.00	0.15
Н	0.1889	0.2007	4.80	5.10					

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

• Lead: 42 Alloy; solder plating

• Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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